TOSHIBA THYRISTOR SILICON PLANAR TYPE

# SF16GZ51, SF16JZ51

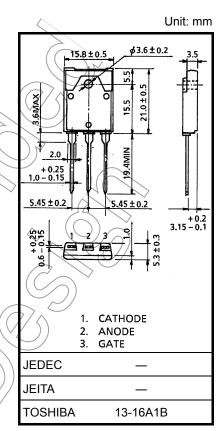
### MEDIUM POWER CONTROL APPLICATIONS

- Repetitive Peak Off-State Voltage: VDRM = 400V,600V
   Repetitive Peak Reverse Voltage: VRRM = 400V,600V
- Average On-State Current: I<sub>T</sub> (AV) = 16A
- Isolation Voltage:  $V_{Isol} = 1500V AC$

#### **MAXIMUM RATINGS**

CHARACTERISTIC		SYMBOL	RATING	UNIT
Repetitive Peak Off-State Voltage and	SF16GZ51	$V_{DRM}$	400	$(\bigcirc \langle \langle \rangle \rangle)$
Repetitive Peak Reverse Voltage	SF16JZ51	$V_{RRM}$	600	V
Non-Repetitive Peak Reverse Voltage	SF16GZ51	V <sub>RSM</sub>	500	\ \ \
(Non-Repetitive <5ms, $T_j = 0\sim125^{\circ}C$ )	SF16JZ51	VRSM	720	V
Average On-State Current (Half Sine Waveform)		I <sub>T(AV)</sub>	16	A
R.M.S On-State Current		I <sub>T(RMS)</sub>	25	< <a>A</a>
Peak One Cycle Surge On-State Current (Non-Repetitive)		ITSM	250 (50Hz) 275 (60Hz)	A
I <sup>2</sup> t Limit Value		(I <sup>2</sup> t \)	312	$A^2$ s
Critical Rate of Rise of C Curret	n-State (Note)	di / dt	100	A/µs
Peak Gate Power Dissip	ation	PGM	5	$\searrow_{W}$
Average Gate Power Dis	sipation	P <sub>G</sub> (AV) $\langle$	(0.5/ ))	W
Peak Forward Gate Voltage		V <sub>FGM</sub>	10	V
Peak Reverse Gate Voltage		V <sub>RGM</sub>	5	V
Peak Forward Gate Current		I <sub>GM</sub>	2	Α
Junction Temperature		₹i <sub>&gt;</sub>	-40~125	°C
Storage Temperature Range		Tstg	-40~125	°C
Isolation Voltage (AC, t = 1min.)		VIsol	1500	V

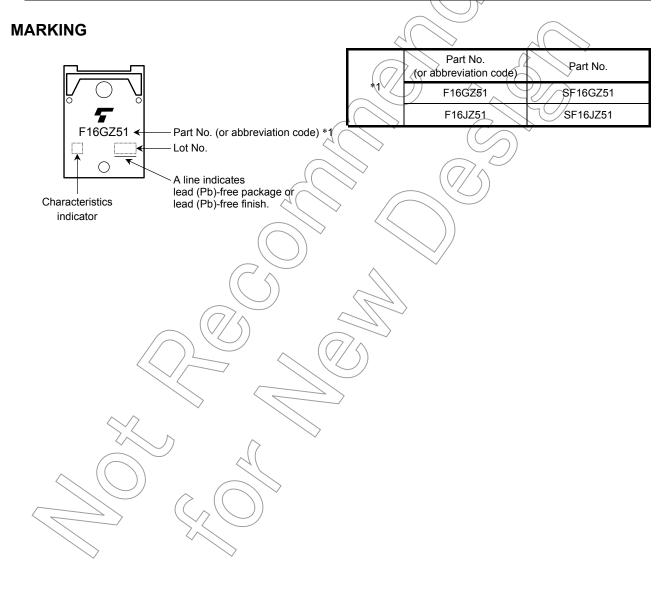
Note: di / dt Test Condition,  $l_G = 30$ mA,  $t_{gw} = 10\mu$ s,  $t_{gr} \le 250$ ns



Weight: 5.9 g (typ.)

## **ELECTRICAL CHARACTERISTICS (Ta = 25°C)**

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Repetitive Peak Off-State Current and Repetitive Peak Reverse Current	I <sub>DRM</sub> I <sub>RRM</sub>	V <sub>DRM</sub> = V <sub>RRM</sub> = Rated	_	_	20	μΑ
Peak On-State Voltage	V <sub>TM</sub>	I <sub>TM</sub> = 50A	_	_	1.5	V
Gate Trigger Voltage	V <sub>GT</sub>	$V_D = 6V$ , $R_1 = 10\Omega$	$\nearrow$	_	1.5	V
Gate Trigger Current	I <sub>GT</sub>	1 VD - 6V, KL - 10Ω	(-)	12	15	mA
Holding Current	lΗ	V <sub>D</sub> = 6V, I <sub>TM</sub> = 500mA		) —	50	mA
Critical Rate of Rise of Off-State Voltage	dv / dt	V <sub>DRM</sub> = Rated, Tc = 125°C Exponential Rise	$\mathcal{D}$	50	_	V / µs
Thermal Resistance	R <sub>th (j-c)</sub>	Junction to Case		_	1.5	°C/W



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(TYPICAL)

 $I_{TM} = 500 mA$ 

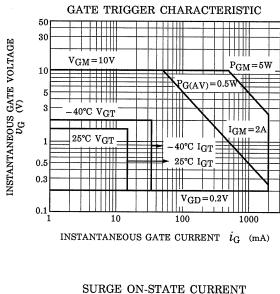
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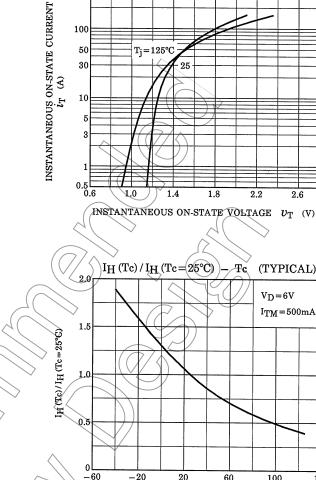
 $V_D = 6V$ 

 $i_{\rm T}$  –  $v_{\rm T}$ 

 $T_j = 125$ °C

25





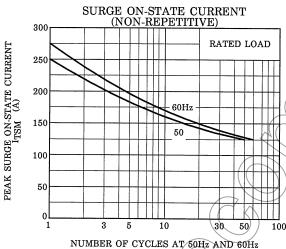
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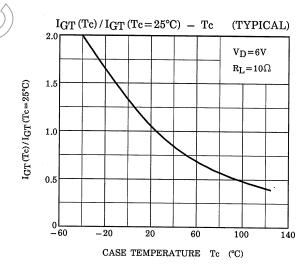
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50

30

10

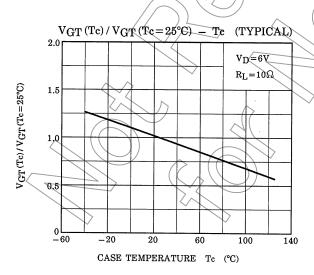


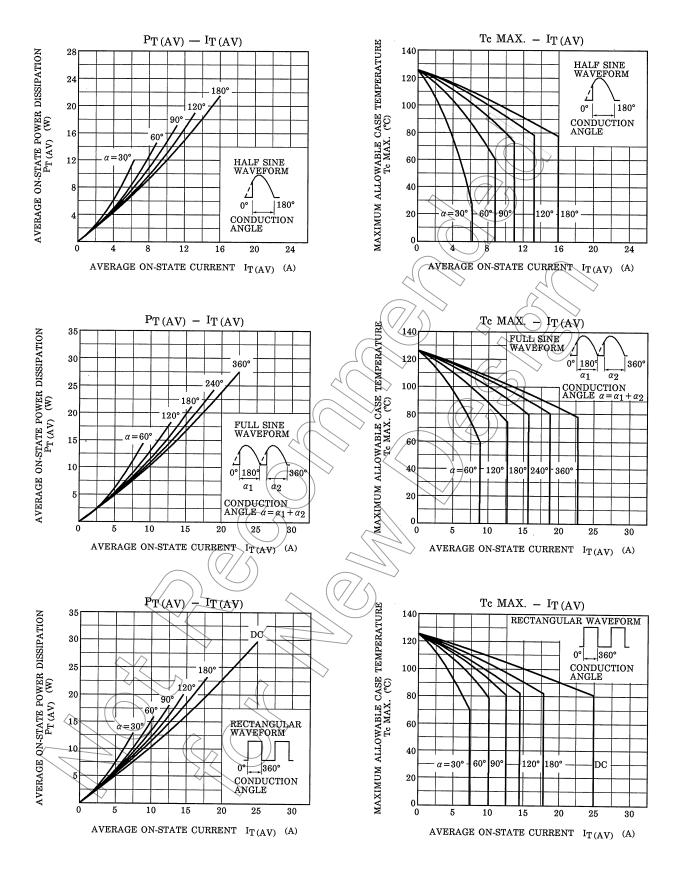


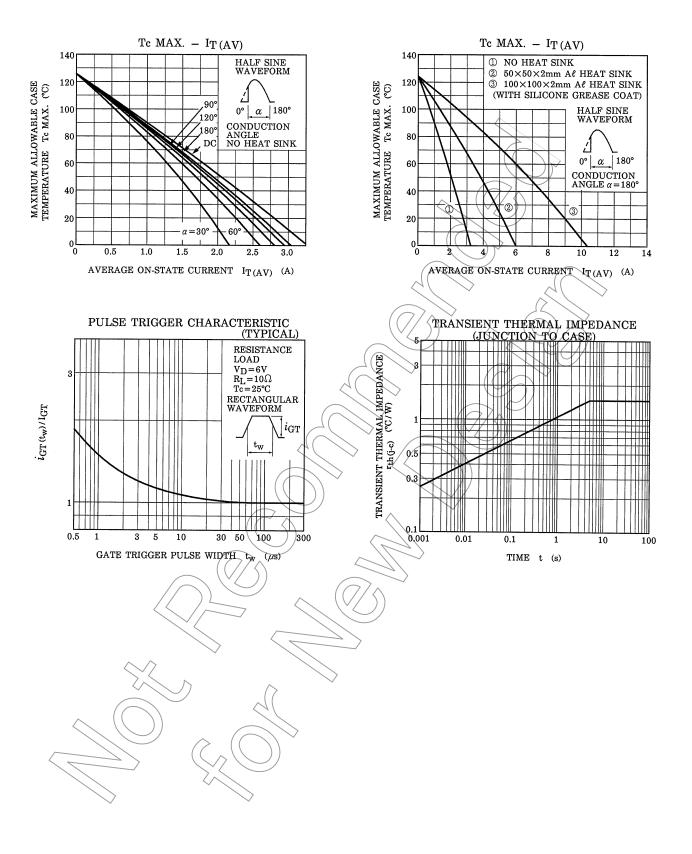
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CASE TEMPERATURE Tc (°C)









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